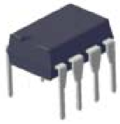
Single-Stage Power Factor Corrected Off-Line Switching Regulator IC

Features and Benefits

- Integrated on-time control circuit (it realizes high power factor by average current control)
- Integrated startup circuit (no external startup circuit necessary)
- Integrated soft-start circuit (reduces power stress during start-up on the incorporated power MOSFET and output rectifier)
- Integrated bias assist circuit (improves startup performance, suppresses VCC voltage droop during operation, and allows use of low-rated ceramic capacitor on VCC pin)
- Integrated Leading Edge Blanking (LEB) circuit
- Integrated maximum on-time limit circuit
- Protection features:
  - Overcurrent protection (OCP): pulse-by-pulse
  - Overvoltage protection (OVP): pins VCC, OVP, and OCP, auto restart
  - Overload protection (OLP): auto restart
  - Thermal shutdown (TSD): latched shutdown

Package: 8-pin DIP



Not to scale

Description

The LC5500 series is the power IC for the LED driver which has an incorporated power MOSFET, designed for input capacitorless applications, and making it possible for systems to comply with the harmonics standard (IEC61000-3-2 class C). The controller adapts the average current control method for realizing high power factors, and the quasi-resonant topology contributes to high efficiency and low EMI noise.

The rich set of protection features helps to realize low component counts, and high performance-to-cost power supply.

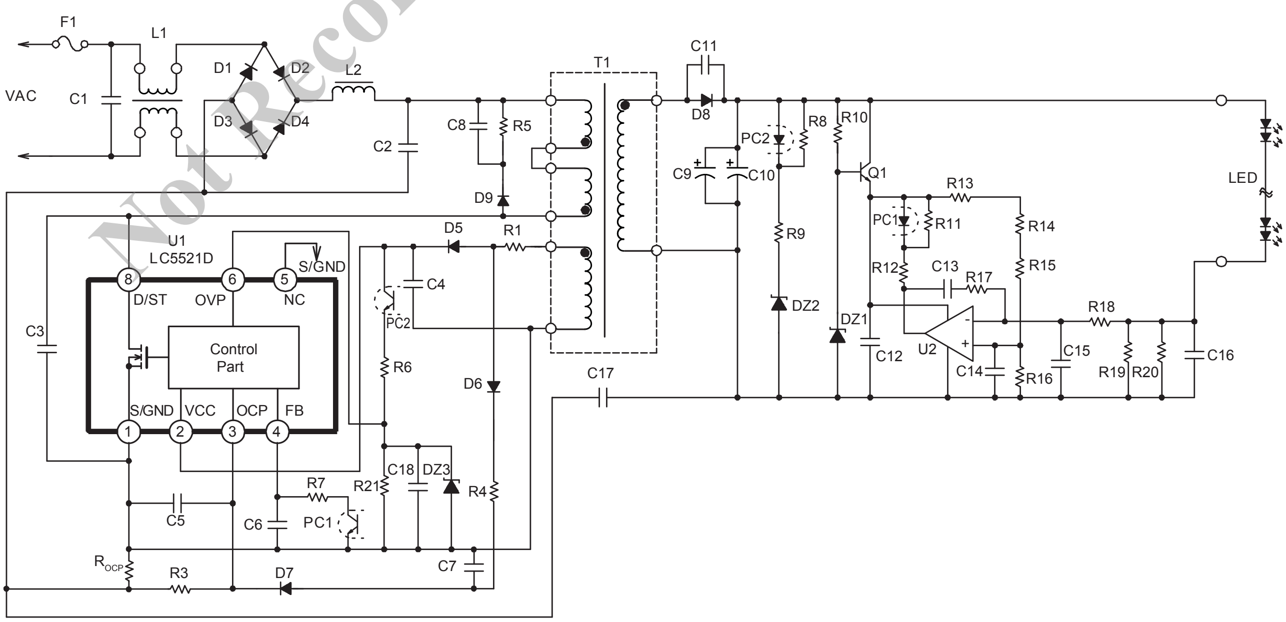
The LC5521D is intended for isolated designs. The incorporated MOSFET has a V_{DSS}(min) rating of 650 V and $R_{DS(on)}$(max) of 3.95 Ω. It is capable of a maximum output power of 13 W on 230 VAC supply and 10 W on universal input supply (85 to 265VAC) based on the thermal rating. Note that the maximum output power can be up to 120% to 140% of this value. However, it may be limited in applications with low output voltage or short duty cycle.

Applications

- LED lighting fixtures
- LED light bulbs

Not Recommended for New Designs

Typical Application



SANKEN ELECTRIC CO., LTD.
http://www.sanken-ele.co.jp/en/

November 26, 2012

Selection Guide

Part Number	Package
LC5521D	DIP8 with pin 7 removed

The polarity value for current specifies a sink as "+," and a source as "−," referencing the IC.

Absolute Maximum Ratings T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Notes	Pins	Rating	Unit
Drain Current[1]	I_{DPeak}	Single pulse	8 – 1	2.5	A
Single Pulse Avalanche Energy[2]	E_{AS}	I_{LPeak} = 2.0 A, V_{DD} = 99 V, L = 20 mH	8 – 1	47	mJ
Control Part Input Voltage	V_{CC}		2 – 1	35	V
OCP Pin Voltage	V_{OCP}		3 – 1	−2.0 to 5.0	V
FB Pin Voltage	V_{FB}		4 – 1	−0.3 to 7.0	V
OVP Pin Voltage	V_{OVP}		6 – 1	−0.3 to 5.0	V
Allowable Power Dissipation of MOSFET[3]	P_{D1}	Mounted on a 15 mm × 15 mm PCB	8 – 1	0.97	W
Operating Ambient Temperature	T_{OP}		—	−55 to 125	°C
Storage Temperature	T_{stg}		—	−55 to 125	°C
Channel Temperature	T_{ch}		—	150	°C

[1]Refer to MOSFET Safe Operating Area Curve.
[2]Refer to MOSFET Avalanche Energy Derating Coefficient Curve.
[3]Refer to MOSFET Temperature versus Power Dissipation Curve.

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ELECTRICAL CHARACTERISTICS of Control Part T_A = 25°C, V_{CC} = 20 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Pins	Min.	Typ.	Max.	Unit
Startup Operation							
Operation Start Voltage	$V_{CC(ON)}$		2 – 1	13.8	15.1	17.3	V
Operation Stop Voltage*	$V_{CC(OFF)}$		2 – 1	8.4	9.4	10.7	V
Operating Current	$I_{CC(ON)}$		2 – 1	–	–	3.7	mA
Startup Circuit Operation Voltage	$V_{STARTUP}$		8 – 1	42	57	72	V
Startup Current	$I_{CC(STARTUP)}$	V_{CC}= 13 V	2 – 1	−5.5	−3.0	−1.0	mA
Startup Current Threshold Biasing Voltage-1*	$V_{CC(BIAS)1}$		2 – 1	9.5	11.0	12.5	V
Startup Current Threshold Biasing Voltage-2	$V_{CC(BIAS)2}$		2 – 1	14.4	16.6	18.8	V
Normal Operation							
PWM Operation Frequency	f_{OSC}		8 – 1	11.0	14.0	18.0	kHz
Maximum On-Time	$t_{ON(MAX)}$		8 – 1	30.0	40.0	50.0	μs
FB Pin Voltage Minimum Limit	$V_{FB(MIN)}$		4 – 1	0.55	0.90	1.25	V
Maximum Feedback Current	$I_{FB(MAX)}$		4 – 1	−40	−25	−10	μA
Leading Edge Blanking Time	$t_{ON(LEB)}$		3 – 1	–	500	–	ns
Quasi-Resonant Operation Threshold Voltage-1	$V_{BD(TH1)}$		3 – 1	0.14	0.24	0.34	V
Quasi-Resonant Operation Threshold Voltage-2	$V_{BD(TH2)}$		3 – 1	0.12	0.17	0.22	V
Protection Operation							
OCP Pin Overcurrent Protection (OCP) Threshold Voltage	V_{OCP}		3 – 1	−0.66	−0.60	−0.54	V
OCP Pin Source Current	I_{OCP}		3 – 1	−120	−40	−10	μA
OCP Pin Overvoltage Protection (OVP) Threshold Voltage	$V_{BD(OVP)}$		3 – 1	2.2	2.6	3.0	V
Overload Protection (OLP) Threshold Voltage-1	$V_{FB(OLP)1}$		4 – 1	5.0	5.5	6.0	V
Overload Protection (OLP) Threshold Voltage-2	$V_{FB(OLP)2}$		4 – 1	4.1	4.5	4.9	V
OVP Pin OVP Threshold Voltage	$V_{OVP(OVP)}$		6 – 1	1.6	2.0	2.4	V
VCC Pin OVP Threshold Voltage	$V_{CC(OVP)}$		2 – 1	28.5	31.5	34.0	V
Thermal Shutdown Activating Temperature	$T_{J(TSD)}$		–	135	–	–	°C

*$V_{CC(BIAS)1}$ > $V_{CC(OFF)}$ always.

Not Recommended for New Designs

ELECTRICAL CHARACTERISTICS of MOSFET T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Test Conditions	Pins	Min.	Typ.	Max.	Unit
Drain-to-Source Breakdown Voltage	V_{DSS}		8 – 1	650	—	—	V
Drain Leakage Current	I_{DSS}		8 – 1	—	—	300	μA
On Resistance	$R_{DS(on)}$		8 – 1	—	—	3.95	Ω
Switching Time	t_f		8 – 1	—	—	250	ns
Thermal Resistance	$R_{\theta ch\text{-}c}$	Between channel and case; case temperature, T_C, measured at the center of the case top surface	—	—	—	42	°C/W

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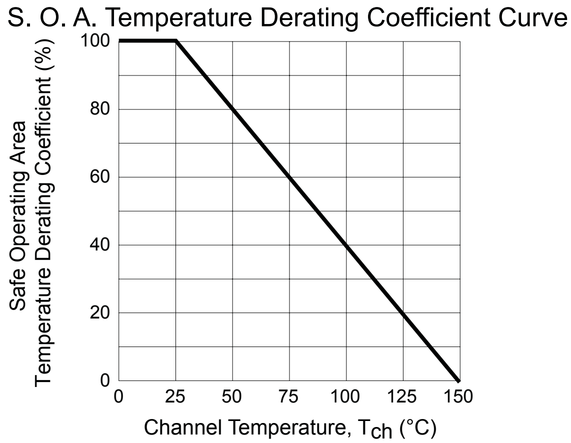
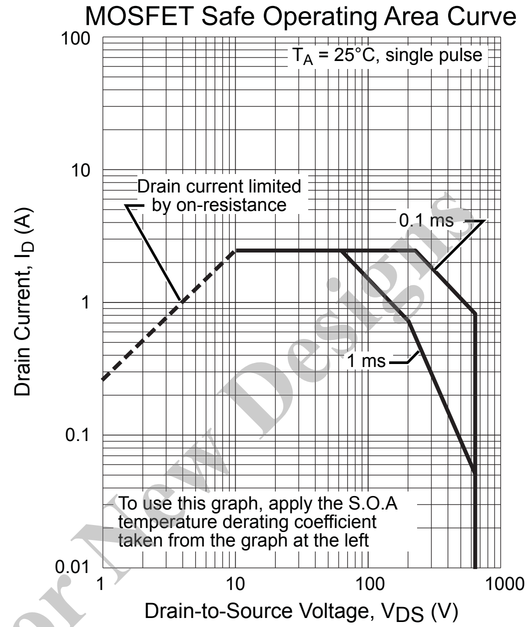
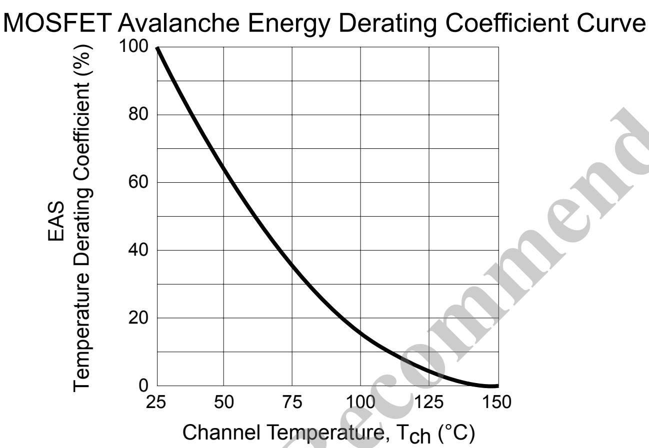
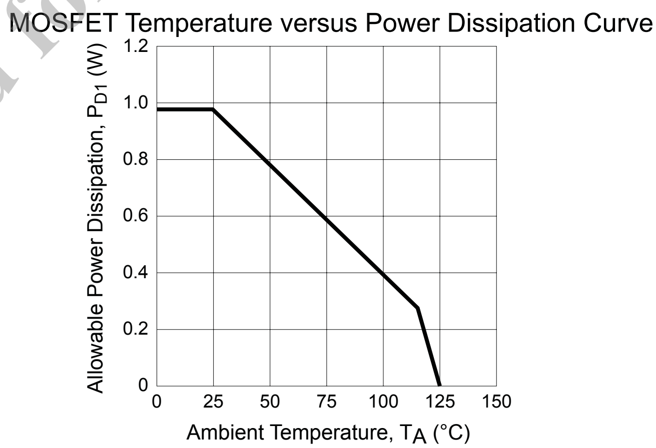
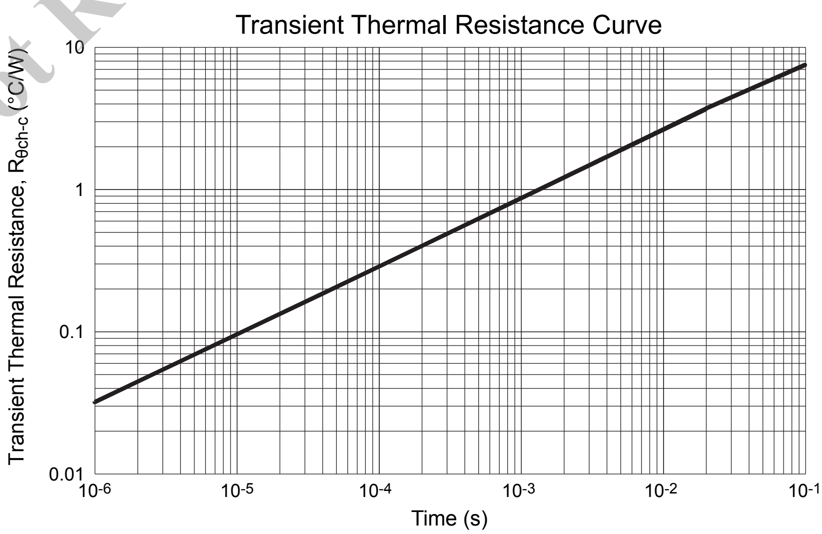
Characteristic Performance











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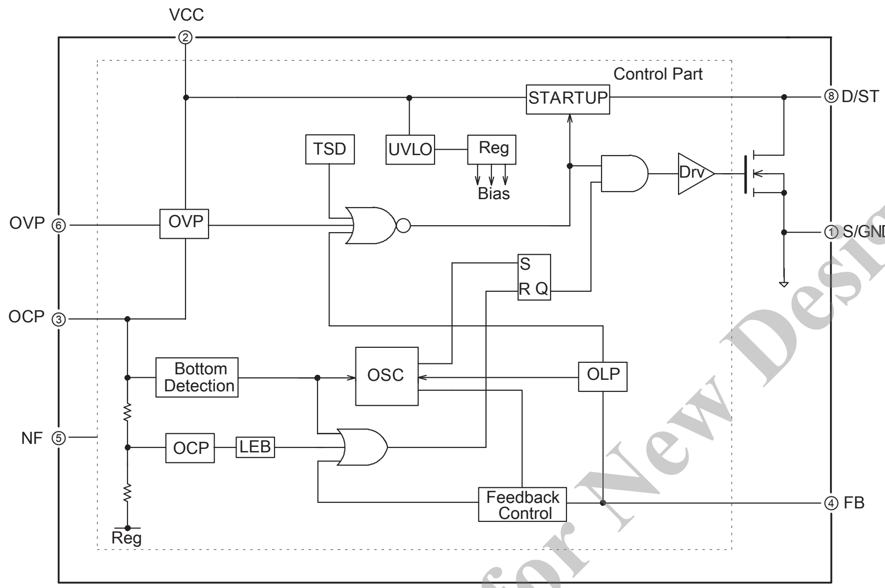
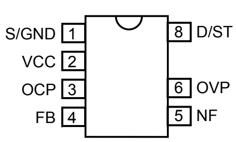
Functional Block Diagram



Pin-out Diagram



LC5521D Pin List Table

Number	Name	Function
1	S/GND	MOSFET source and GND pin for the Control Part
2	VCC	Supply voltage input and Overvoltage protection (OVP) signal input
3	OCP	Overcurrent Protection, quasi-resonant signal input pin, and Overvoltage Protection (OVP) signal input
4	FB	Feedback signal input and Overload Protection (OLP) signal input
5	NF	No function; must be externally connected to S/GND pin with as short a trace as possible, for stable operation of the IC
6	OVP	Overvoltage Protection (OVP) signal input
7	–	Pin removed
8	D/ST	MOSFET drain pin and input of the startup current

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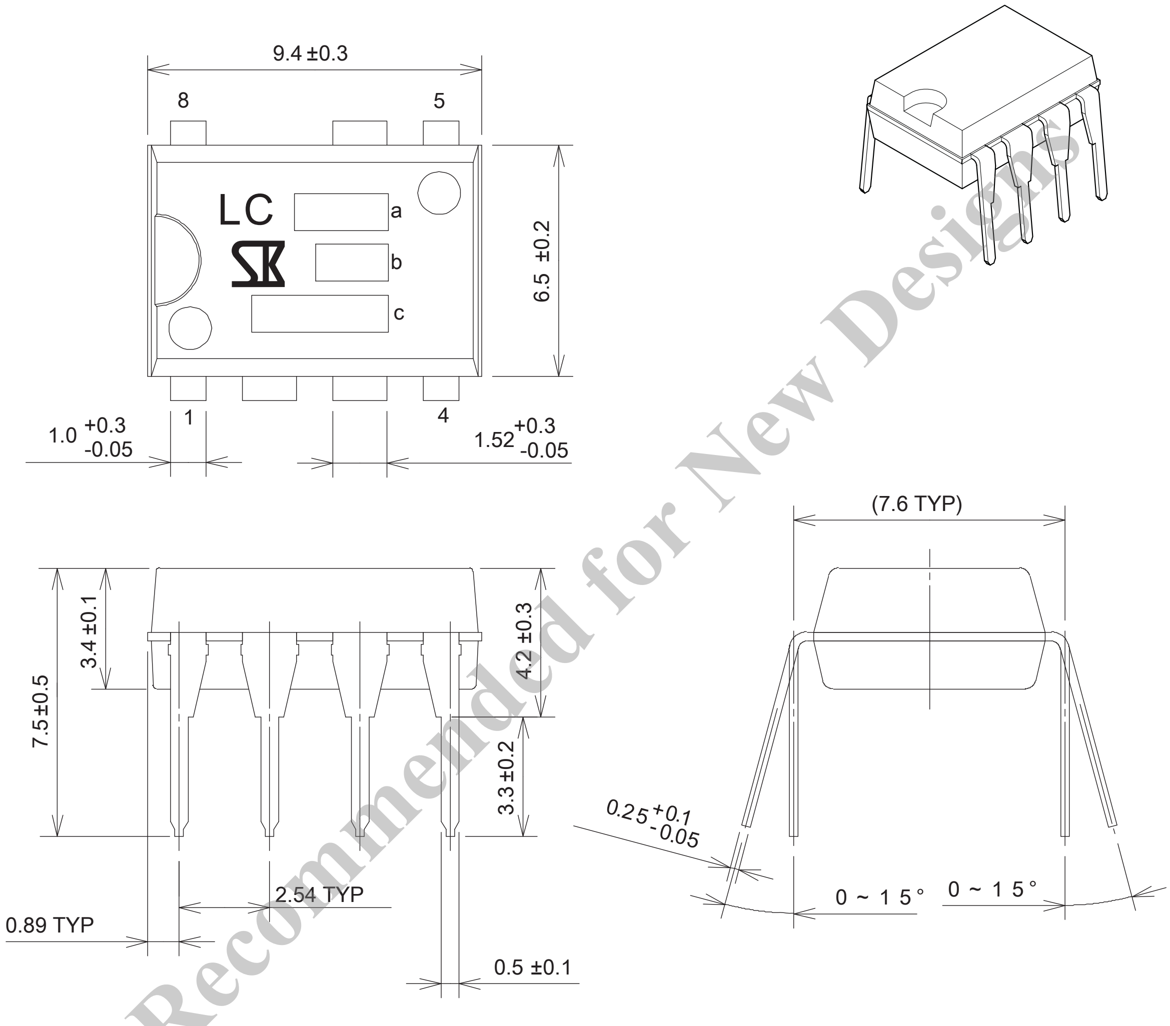
Package Outline Drawing, DIP8



Unit: mm

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a: Part # LC5521
b: SK logo + 3-digit lot number
1st letter: Last digit of year
2nd letter: Month
Jan to September: Numeric
October: O
November: N
December: D
3rd letter: Week
Date 1 to 10: 1
Date 11 to 20: 2
Date 21 to 31: 3
c: Sanken control number

Pb-free. Device composition compliant with the RoHS directive.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

  Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials Inc.
SC102	Dow Corning Toray Co., Ltd.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
  260±5°C 10±1 s (Flow, 2 times)
  380±10°C 3.5±0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 1.5 mm from the body of the products.

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

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  In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.
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